8-input NAND gate

Rev. 1 — 20 November 2013

**Product data sheet** 

### 1. General description

The 74AHC30-Q100; 74AHCT30-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC30-Q100; 74AHCT30-Q100 provides an 8-input NAND function.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V<sub>CC</sub>
- Input levels:
  - For 74AHC30-Q100: CMOS level
  - For 74AHCT30-Q100: TTL level
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

# 3. Ordering information

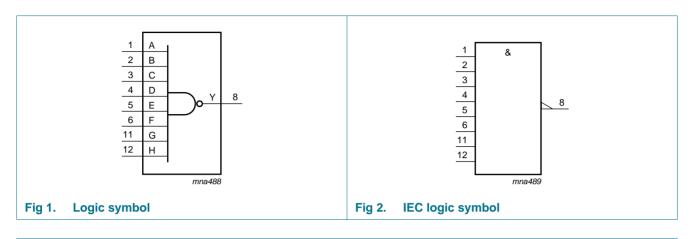
### Table 1.Ordering information

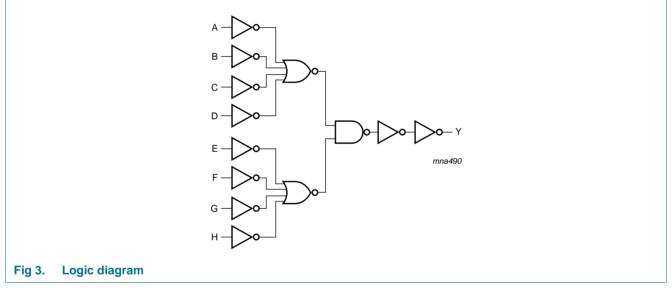
Type number	Package									
	Temperature range	Name	Description	Version						
74AHC30D-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	SOT108-1						
74AHCT30D-Q100			body width 3.9 mm							
74AHC30PW-Q100	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package;	SOT402-1						
74AHCT30PW-Q100			14 leads; body width 4.4 mm							
74AHC30BQ-Q100	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced	SOT762-1						
74AHCT30BQ-Q100			very thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm							

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8-input NAND gate

# 4. Functional diagram

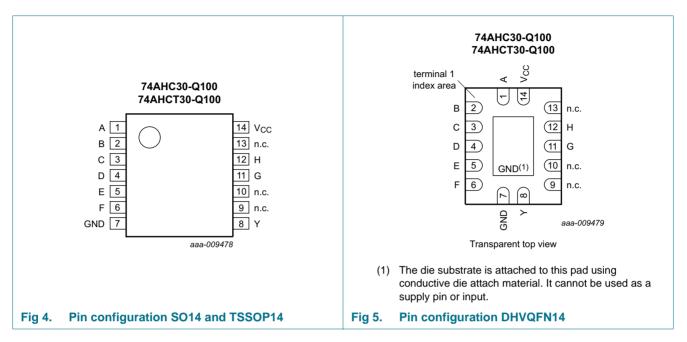




74AHC\_AHCT30\_Q100

# 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
A	1	data input
В	2	data input
С	3	data input
D	4	data input
E	5	data input
F	6	data input
GND	7	ground (0 V)
Y	8	data output
n.c.	9	not connected
n.c.	10	not connected
G	11	data input
Н	12	data input
n.c.	13	not connected
V <sub>CC</sub>	14	supply voltage

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# 6. Functional description

Table 3.	Function	table <sup>[1]</sup>						
Input								Output
Α	В	С	D	E	F	G	Н	Y
L	Х	Х	Х	Х	Х	Х	Х	Н
Х	L	Х	Х	Х	Х	Х	Х	Н
Х	Х	L	Х	Х	Х	Х	Х	Н
Х	Х	Х	L	Х	Х	Х	Х	Н
Х	Х	Х	Х	L	Х	Х	Х	Н
Х	Х	Х	Х	Х	L	Х	Х	Н
Х	Х	Х	Х	Х	Х	L	Х	Н
Х	Х	Х	Х	Х	Х	Х	L	Н
Н	Н	Н	Н	Н	Н	Н	Н	L

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

# 7. Limiting values

#### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Parameter	Conditions	Min	Max	Unit
supply voltage		-0.5	+7.0	V
input voltage		-0.5	+7.0	V
input clamping current	V <sub>I</sub> < -0.5 V	<u>[1]</u> –20	-	mA
output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> –20	+20	mA
output current	$V_{O}$ = -0.5 V to (V <sub>CC</sub> + 0.5 V)	-25	+25	mA
supply current		-	+75	mA
ground current		-75	-	mA
storage temperature		-65	+150	°C
total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	500	mW
	supply voltage input voltage input clamping current output clamping current output current supply current ground current storage temperature	supply voltageinput voltageinput clamping current $V_I < -0.5 V$ output clamping current $V_O < -0.5 V \text{ or } V_O > V_{CC} + 0.5 V$ output current $V_O = -0.5 V \text{ to } (V_{CC} + 0.5 V)$ supply currentground currentstorage temperature	supply voltage       -0.5         input voltage       -0.5         input voltage       -0.5         input clamping current $V_1 < -0.5 V$ 11 -20         output clamping current $V_0 < -0.5 V \text{ or } V_0 > V_{CC} + 0.5 V$ 11 -20         output current $V_0 = -0.5 V \text{ to } (V_{CC} + 0.5 V)$ -25         supply current       -       -         ground current       -75       -75         storage temperature       -65       -65	supply voltage       -0.5       +7.0         input voltage       -0.5       +7.0         input clamping current $V_1 < -0.5 V$ 11 -20       -         output clamping current $V_0 < -0.5 V$ or $V_0 > V_{CC} + 0.5 V$ 11 -20       +20         output current $V_0 = -0.5 V$ to $(V_{CC} + 0.5 V)$ -25       +25         supply current       -       +75       -         ground current       -75       -       -         storage temperature       -65       +150       -

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SO14 packages: above 70 °C the value of P<sub>tot</sub> derates linearly at 8 mW/K.
 For TSSOP14 packages: above 60 °C the value of P<sub>tot</sub> derates linearly at 5.5 mW/K.
 For DHVQFN14 packages: above 60 °C the value of P<sub>tot</sub> derates linearly at 4.5 mW/K.

### 8. Recommended operating conditions

### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter Conditions		74 <i>A</i>	74A	Unit				
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise	$V_{CC}$ = 3.3 V $\pm$ 0.3 V	-	-	100	-	-	-	ns/V
	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V

# 9. Static characteristics

#### Table 6.Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC3	0-Q100									
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	$V_{CC} = 2.0 V$	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		$V_{CC} = 5.5 V$	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_{O}$ = –50 $\mu A;$ $V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O}$ = –50 $\mu A;$ $V_{CC}$ = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		$I_O$ = –50 $\mu A; V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_O = 50 \ \mu\text{A}; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \ \mu\text{A}; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		$I_{O}$ = 8.0 mA; $V_{CC}$ = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	2.0	-	20	-	40	μA
CI	input capacitance	$V_1 = V_{CC}$ or GND	-	3	10	-	10	-	10	pF

8-input NAND gate

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Co	output capacitance		-	4	-	-	-	-	-	pF
74AHCT	30-Q100									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>OH</sub> HIGH-level		$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -8.0 \text{ mA}$	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
lı	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μΑ
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	2.0	-	20	-	40	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other pins at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
CI	input capacitance	$V_{I} = V_{CC} \text{ or } GND$	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF

### Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

# **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 7.

Symbol	Parameter	Conditions	Conditions		25 °C		-40 °C te	o +85 °C	–40 °C to +125 °C		Unit
					Typ[1]	Max	Min	Max	Min	Max	
74AHC3	0-Q100										
t <sub>pd</sub>	propagation delay	A, B, C, D, E, F, G, H to Y; see <u>Figure 6</u> and <u>7</u>	[2]								
		$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	5.0	9.5	1.0	11.0	1.0	12.0	ns
		C <sub>L</sub> = 50 pF		-	6.7	12.0	1.0	14.5	1.0	15.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	3.6	6.5	1.0	7.5	1.0	8.0	ns
		C <sub>L</sub> = 50 pF		-	4.9	8.0	1.0	9.5	1.0	10.5	ns

### Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 7.

Symbol	Parameter	Conditions			25 °C		–40 °C te	o +85 °C	–40 °C to +125 °C		Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V <sub>I</sub> = GND to V <sub>CC</sub>	<u>[3]</u>	-	10	-	-	-	-	-	pF
74AHCT	30-Q100; V <sub>CC</sub>	= 4.5 V to 5.5 V									
t <sub>pd</sub> propagation delay		A, B, C, D, E, F, G, H to Y; see <u>Figure 6</u> and <u>7</u>	[2]								
		C <sub>L</sub> = 15 pF		-	3.3	6.5	1.0	7.5	1.0	8.0	ns
		C <sub>L</sub> = 50 pF		-	4.7	8.5	1.0	9.5	1.0	10.5	ns
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V <sub>I</sub> = GND to V <sub>CC</sub>	<u>[3]</u>	-	12	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage ( $V_{CC}$  = 3.3 V and  $V_{CC}$  = 5.0 V).

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i = input frequency in MHz;$ 

 $f_o = output frequency in MHz;$ 

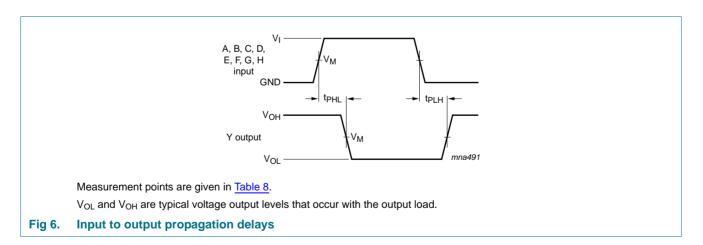
 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

### 11. Waveforms



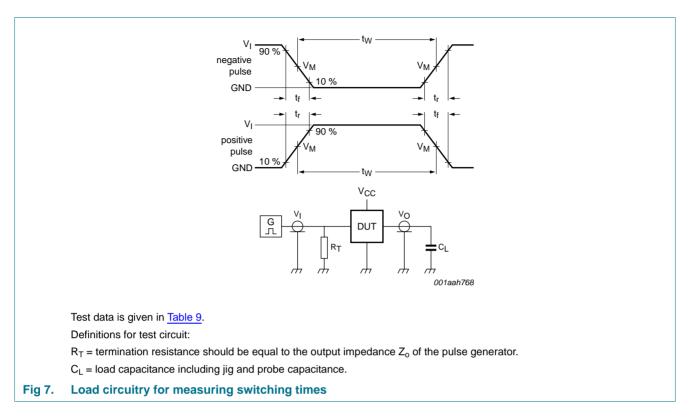
#### Table 8.Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74AHC30-Q100	$0.5  imes V_{CC}$	$0.5  imes V_{CC}$
74AHCT30-Q100	1.5 V	$0.5 \times V_{CC}$

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# 74AHC30-Q100; 74AHCT30-Q100

8-input NAND gate

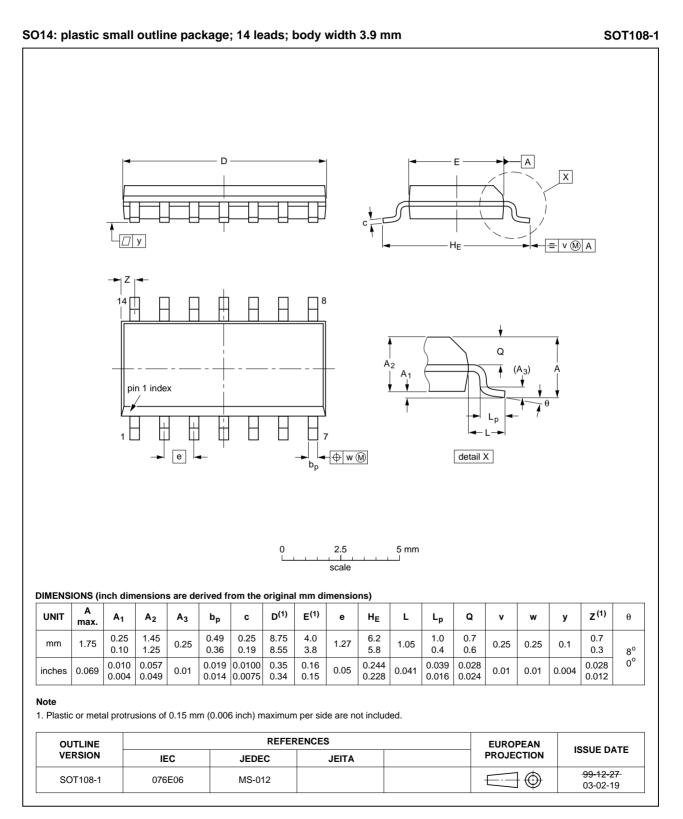


#### Table 9. Test data

Туре	Input	Input L		Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74AHC30-Q100	V <sub>CC</sub>	$\leq$ 3.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>
74AHCT30-Q100	3.0 V	$\leq$ 3.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

8-input NAND gate

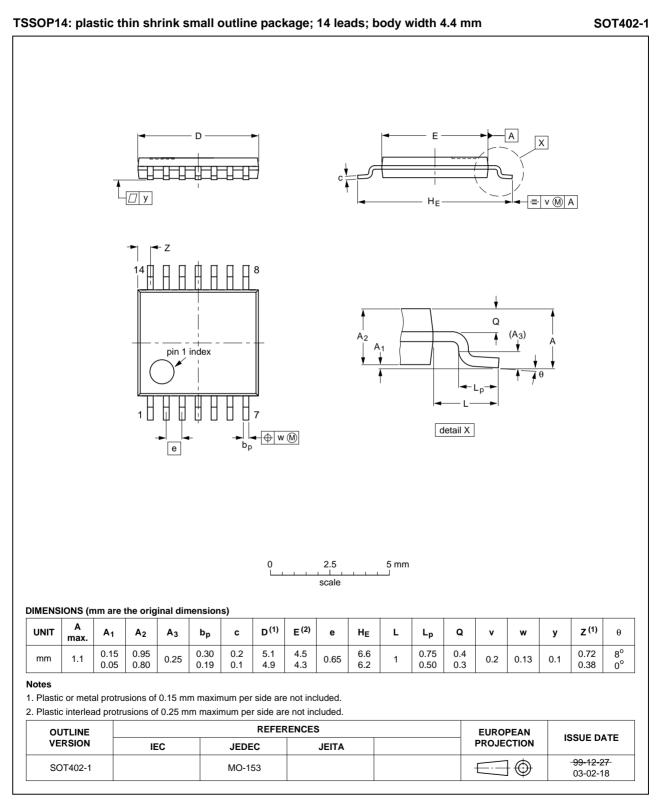
### 12. Package outline



#### Fig 8. Package outline SOT108-1 (SO14)

74AHC\_AHCT30\_Q100

8-input NAND gate

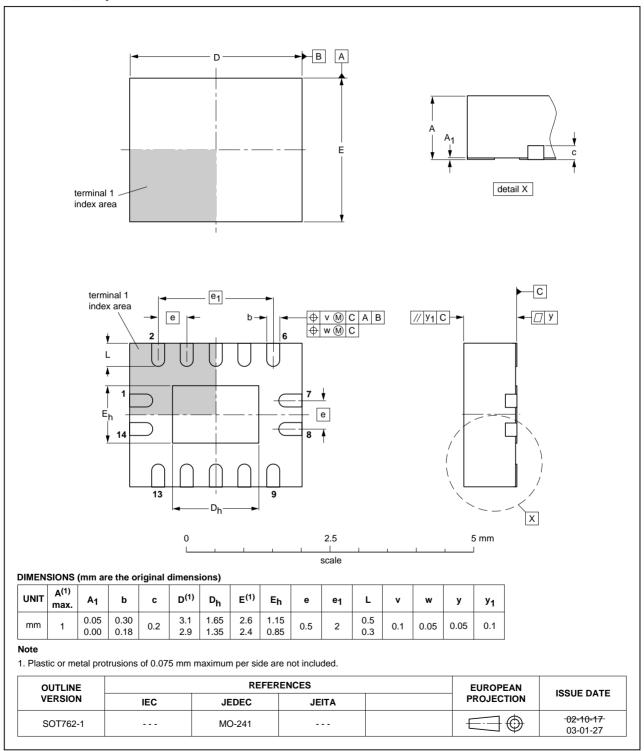


### Fig 9. Package outline SOT402-1 (TSSOP14)

74AHC\_AHCT30\_Q100

Product data sheet

8-input NAND gate



DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

### Fig 10. Package outline SOT762-1 (DHVQFN14)

74AHC\_AHCT30\_Q100

Product data sheet

# **13. Abbreviations**

Table 10.	Abbreviations
Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MIL	Military
MM	Machine Model

# 14. Revision history

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AHC_AHCT30_Q100 v1.	20131120	Product data sheet	-	-	

# **15. Legal information**

### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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# **Mouser Electronics**

Authorized Distributor

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Nexperia:

 74AHCT30BQ-Q100X
 74AHCT30D-Q100J
 74AHC30D-Q100J
 74AHCT30PW-Q100J
 74AHC30PW-Q100J

 74AHC30BQ-Q100X
 74AHC30DQ
 74AHC30PW-Q100J
 74AHC30PW-Q100J
 74AHC30PW-Q100J